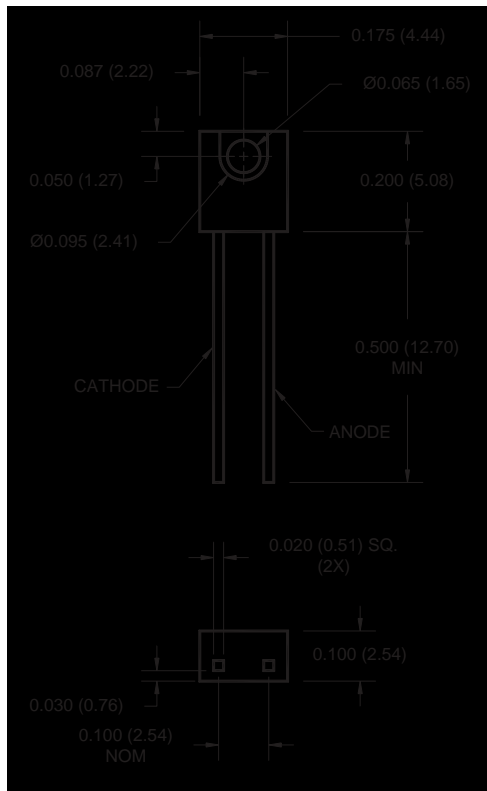


# PLASTIC INFRARED LIGHT EMITTING DIODE

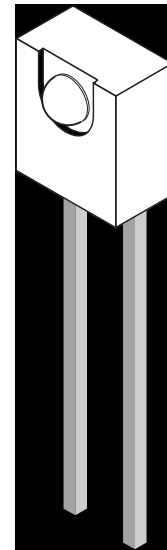
QEE122 QEE123

## PACKAGE DIMENSIONS

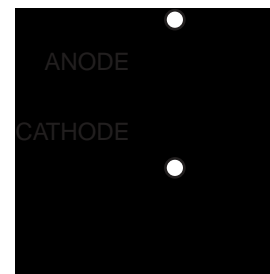


### NOTES:

1. Dimensions for all drawings are in inches (mm).
2. Tolerance of  $\pm .010$  (.25) on all non-nominal dimensions unless otherwise specified.



## SCHEMATIC



## DESCRIPTION

The QEE12X is a 880 nm AlGaAs LED encapsulated in a medium wide angle, plastic sidelooker package.

## FEATURES

- $\lambda = 880$  nm
- Package Type = Sidelooker
- Chip Material = AlGaAs
- Matched Photosensor: QSE113
- Medium Wide Emission Angle,  $50^\circ$
- Package Material: Clear Epoxy
- High Output Power
- Orange stripe on the top side

# PLASTIC INFRARED LIGHT EMITTING DIODE

**QEE122 QEE123**

## ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Rating	Unit
Operating Temperature	$T_{\text{OPR}}$	-40 to + 100	$^\circ\text{C}$
Storage Temperature	$T_{\text{STG}}$	-40 to + 100	$^\circ\text{C}$
Soldering Temperature (Iron) <sup>(2,3,4)</sup>	$T_{\text{SOL-I}}$	240 for 5 sec	$^\circ\text{C}$
Soldering Temperature (Flow) <sup>(2,3)</sup>	$T_{\text{SOL-F}}$	260 for 10 sec	$^\circ\text{C}$
Continuous Forward Current	$I_F$	50	mA
Reverse Voltage	$V_R$	5	V
Power Dissipation <sup>(1)</sup>	$P_D$	100	mW

### NOTES:

1. Derate power dissipation linearly 1.33 mW/ $^\circ\text{C}$  above 25 $^\circ\text{C}$ .
2. RMA flux is recommended.
3. Methanol or isopropyl alcohols are recommended as cleaning agents.
4. Soldering iron 1/16" (1.6 mm) minimum from housing

## ELECTRICAL / OPTICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )

Parameter	Test Conditions	Symbol	Min	Typ	Max	Units
Peak Emission Wavelength	$I_F = 100 \text{ mA}$	$\lambda_{\text{PE}}$	—	880	—	nm
Emission Angle	$I_F = 100 \text{ mA}$	$2\theta_{1/2}$	—	50	—	Deg.
Forward Voltage	$I_F = 100 \text{ mA}$ , $t_p = 20 \text{ ms}$	$V_F$	—	—	1.7	V
Reverse Current	$V_R = 5 \text{ V}$	$I_R$	—	—	10	$\mu\text{A}$
Radiant Intensity QEE122	$I_F = 100 \text{ mA}$ , $t_p = 20 \text{ ms}$	$I_E$	4	—	16	mW/sr
Radiant Intensity QEE123	$I_F = 100 \text{ mA}$ , $t_p = 20 \text{ ms}$	$I_E$	8	—	—	mW/sr
Rise Time	$I_F = 100 \text{ mA}$	$t_r$	—	800	—	ns
Fall Time		$t_f$	—	800	—	ns

# PLASTIC INFRARED LIGHT EMITTING DIODE

QEE122 QEE123

Fig.1 Normalized Radiant Intensity vs. Forward Current

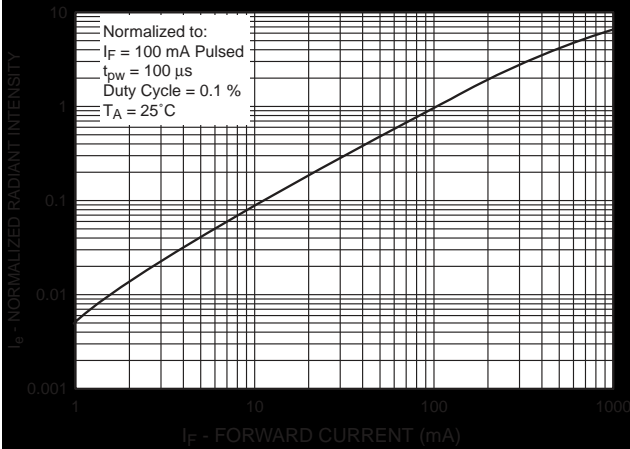


Fig.2 Coupling Characteristics of QEE123 And QSE113

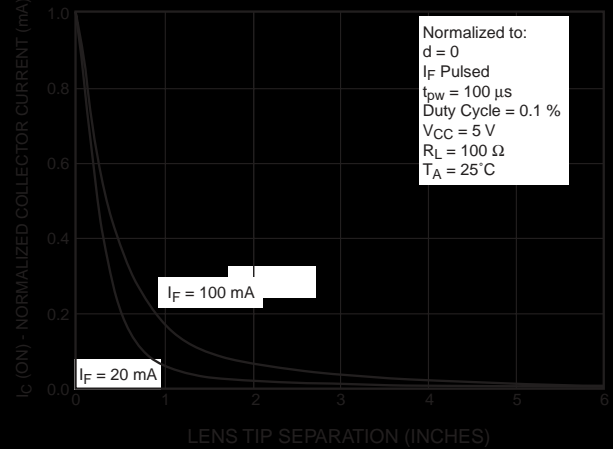


Fig.3 Forward Voltage vs. Ambient Temperature

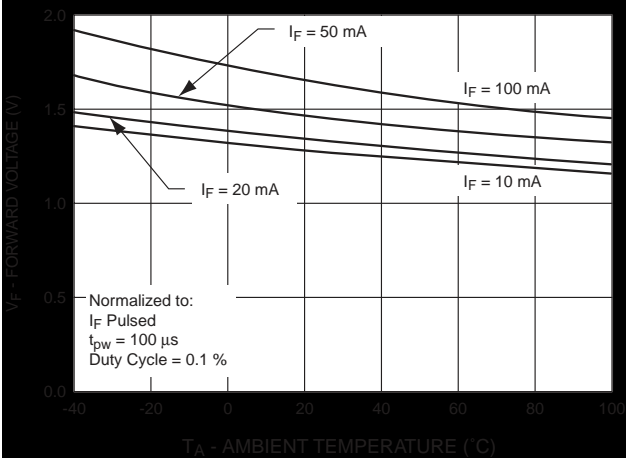


Fig. 4 Normalized Intensity vs. Wavelength

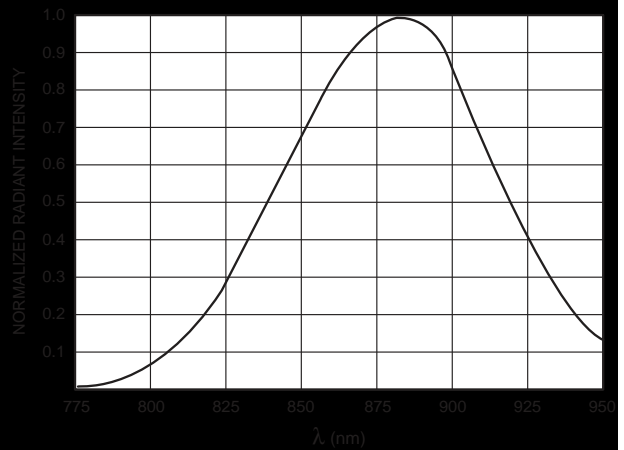
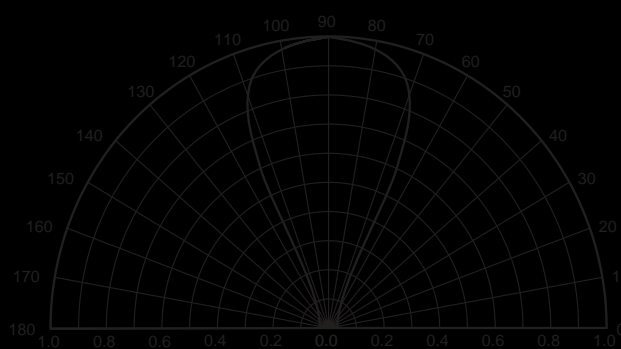


Fig. 5 Radiation Diagram





# PLASTIC INFRARED LIGHT EMITTING DIODE

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**QEE122 QEE123**

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.